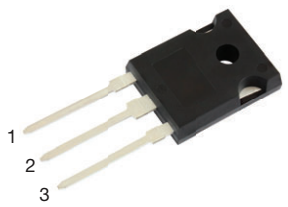
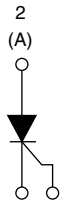
Thyristor High Voltage, Phase Control SCR, 30 A



TO-247AD 3L



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FEATURES

- Designed and qualified according to JEDEC® - JESD 47
- Flexible solution for reliable AC power rectification
- Easy control peak current at charger power up to reduce passive / electromechanical components
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

RoHS COMPLIANT
HALOGEN FREE

APPLICATIONS

- Typical usage is in input rectification crowbar (soft start) and AC switch in motor control, UPS, welding and battery charge

DESCRIPTION

The VS-30TPS12L-M3 high voltage series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications.
AEC-Q101 qualified P/N available (VS-30TPS12LHM3).

PRIMARY CHARACTERISTICS	
$I_{T(AV)}$	20 A
V_{DRM}/V_{RRM}	1200 V
V_{TM}	1.3 V
I_{GT}	45 mA
T_J	-40 °C to +125 °C
Package	TO-247AD 3L
Circuit configuration	Single SCR

MAJOR RATINGS AND CHARACTERISTICS			
PARAMETER	TEST CONDITIONS	VALUES	UNITS
$I_{T(AV)}$	Sinusoidal waveform	20	A
I_{RMS}		30	
V_{RRM}/V_{DRM}		1200	V
I_{TSM}		300	A
V_T	20 A, T_J = 25 °C	1.3	V
dv/dt		500	V/μs
di/dt		150	A/μs
T_J		-40 to +125	°C

VOLTAGE RATINGS			
PART NUMBER	V_{RRM}/V_{DRM}, MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	V_{RSM}, MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I_{RRM}/I_{DRM} AT 125 °C mA
VS-30TPS12L-M3	1200	1300	10

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ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum average on-state current	$I_{T(AV)}$	T_C = 95 °C, 180° conduction half sine wave	20	A
Maximum RMS on-state current	I_{RMS}		30	
Maximum peak, one-cycle non-repetitive surge current	I_{TSM}	10 ms sine pulse, rated V_{RRM} applied	250	
		10 ms sine pulse, no voltage reapplied	300	
Maximum I^2t for fusing	I^2t	10 ms sine pulse, rated V_{RRM} applied	310	A^2s
		10 ms sine pulse, no voltage reapplied	442	
Maximum $I^2\sqrt{t}$ for fusing	$I^2\sqrt{t}$	t = 0.1 ms to 10 ms, no voltage reapplied	4420	$A^2\sqrt{s}$
Maximum on-state voltage drop	V_{TM}	20 A, T_J = 25 °C	1.3	V
On-state slope resistance	r_t	T_J = 125 °C	12	mΩ
Threshold voltage	$V_{T(TO)}$		1.0	V
Maximum reverse and direct leakage current	I_{RM}/I_{DM}	T_J = 25 °C; V_R = rated V_{RRM} / V_{DRM}	0.5	mA
		T_J = 125 °C	10	
Maximum holding current	I_H	Anode supply = 6 V, resistive load, initial I_T = 1 A, T_J = 25 °C	150	
Maximum latching current	I_L	Anode supply = 6 V, resistive load, T_J = 25 °C	200	
Maximum rate of rise of off-state voltage	dv/dt	T_J = T_J maximum, linear to 80 % V_{DRM}, R_g-k = open	500	V/µs
Maximum rate of rise of turned-on current	di/dt		150	A/µs

TRIGGERING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum peak gate power	P_{GM}		8.0	W
Maximum average gate power	$P_{G(AV)}$		2.0	
Maximum peak positive gate current	$+I_{GM}$		1.5	A
Maximum peak negative gate voltage	$-V_{GM}$		10	V
Maximum required DC gate current to trigger	I_{GT}	Anode supply = 6 V, resistive load, T_J = -10 °C	60	mA
		Anode supply = 6 V, resistive load, T_J = 25 °C	45	
		Anode supply = 6 V, resistive load, T_J = 125 °C	20	
Maximum required DC gate voltage to trigger	V_{GT}	Anode supply = 6 V, resistive load, T_J = -10 °C	2.5	V
		Anode supply = 6 V, resistive load, T_J = 25 °C	2.0	
		Anode supply = 6 V, resistive load, T_J = 125 °C	1.0	
Maximum DC gate voltage not to trigger	V_{GD}	T_J = 125 °C, V_{DRM} = rated value	0.25	
Maximum DC gate current not to trigger	I_{GD}		2.0	mA

SWITCHING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Typical turn-on time	t_{gt}	T_J = 25 °C	0.9	µs
Typical reverse recovery time	t_{rr}	T_J = 125 °C	4	
Typical turn-off time	t_q		110	

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THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range		T_J, T_{Stg}		-40 to 125	°C
Maximum thermal resistance, junction to case		R_{thJC}	DC operation	0.8	°C/W
Maximum thermal resistance, junction to ambient		R_{thJA}	DC operation	40	°C/W
Maximum thermal resistance, case to heatsink		R_{thCS}	Mounting surface, smooth and greased	0.25	°C/W
Approximate weight				6	g
				0.21	oz.
Mounting torque	minimum			6 (5)	kgf · cm (lbf · in)
	maximum			12 (10)	kgf · cm (lbf · in)
Marking device			Case style TO-247AD 3L	30TPS12L	

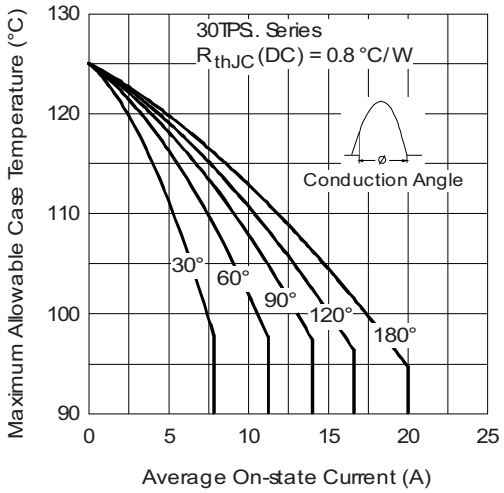

Fig. 1 - Current Rating Characteristics

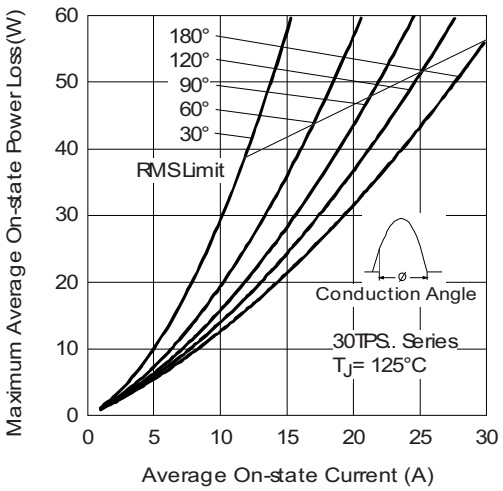

Fig. 3 - On-State Power Loss Characteristics

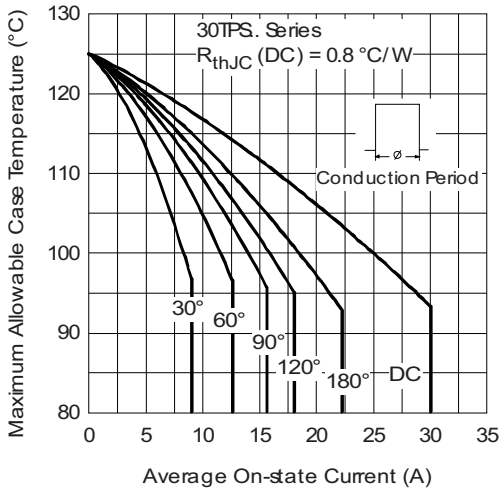

Fig. 2 - Current Rating Characteristics

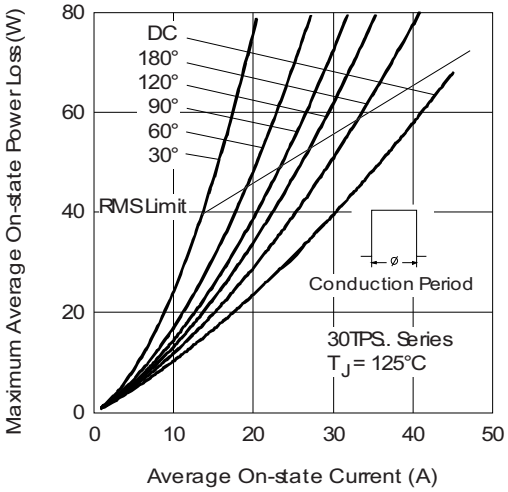

Fig. 4 - On-State Power Loss Characteristics

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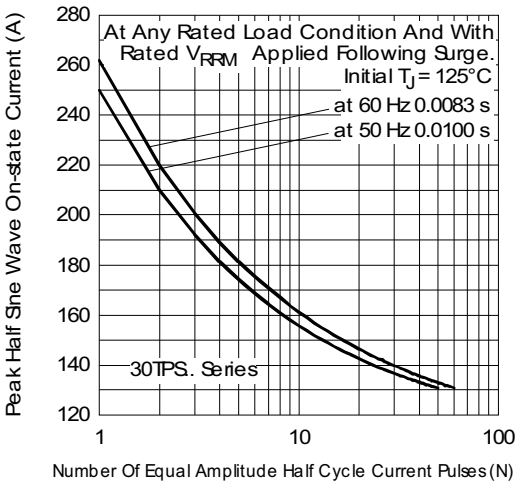

Fig. 5 - Maximum Non-Repetitive Surge Current

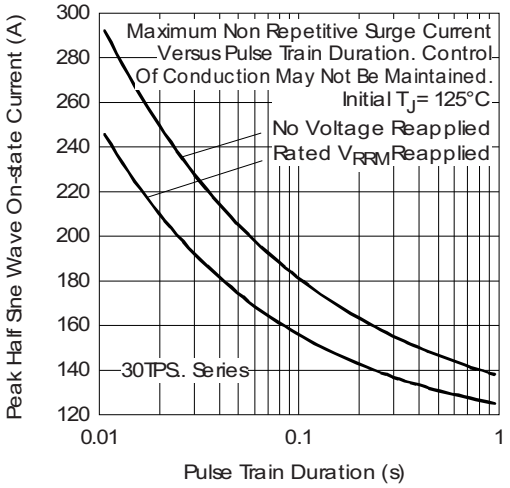

Fig. 6 - Maximum Non-Repetitive Surge Current

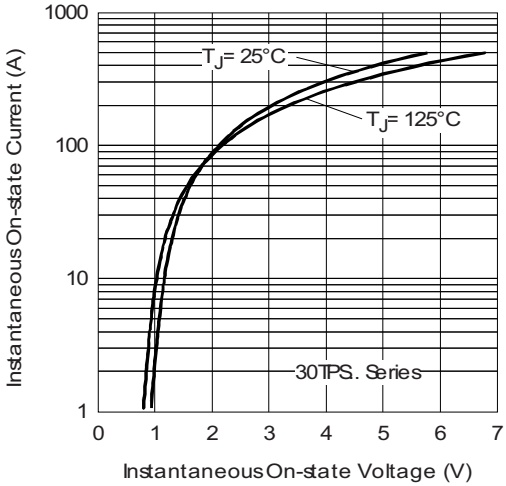

Fig. 7 - On-State Voltage Drop Characteristics

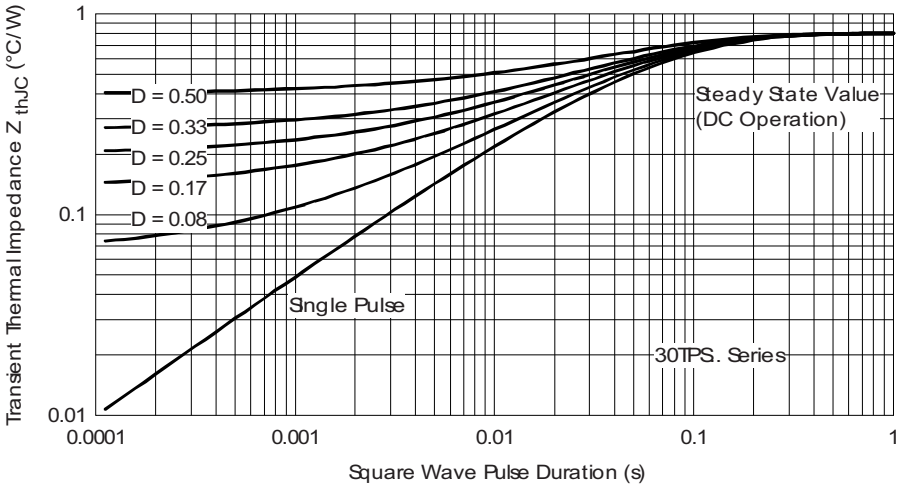

Fig. 8 - Thermal Impedance Z_{thJC} Characteristics

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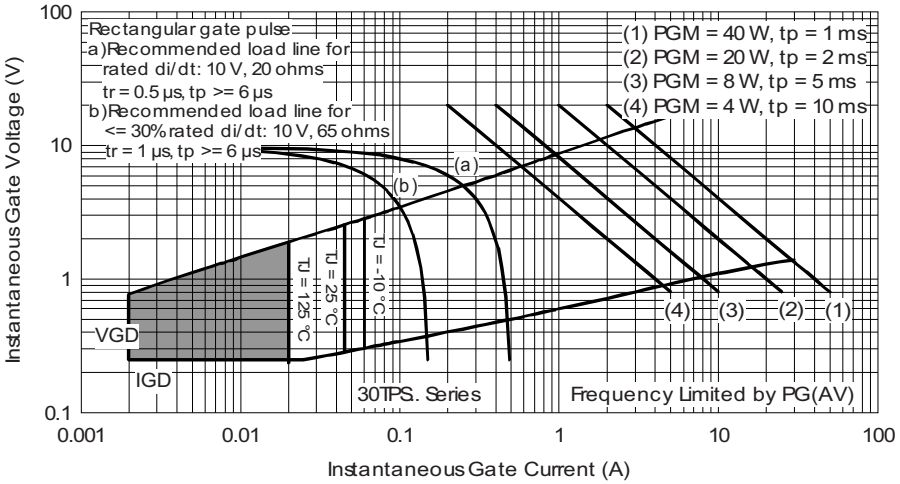

Fig. 9 - Gate Characteristics

ORDERING INFORMATION TABLE

Device code

VS-	30	T	P	S	12	L	-M3
1	2	3	4	5	6	7	8

1 - Vishay Semiconductors product

2 - Current rating (30 = 30 A)

3 - Circuit configuration:
T = Thyristor

4 - P = TO-247 package

5 - Type of silicon:
S = Standard recovery rectifier

6 - Voltage code x 100 = V_{RRM} — 12 = 1200 V

7 - Package L = long lead

8 - Environmental digit:
-M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)			
PREFERRED P/N	**QUANTITY PER TUBE**	**MINIMUM ORDER QUANTITY**	**PACKAGING DESCRIPTION**
VS-30TPS12L-M3	25	500	Antistatic plastic tubes

LINKS TO RELATED DOCUMENTS		
Dimensions	TO-247AD 3L	www.vishay.com/doc?95626
Part marking information	TO-247AD 3L	www.vishay.com/doc?95007

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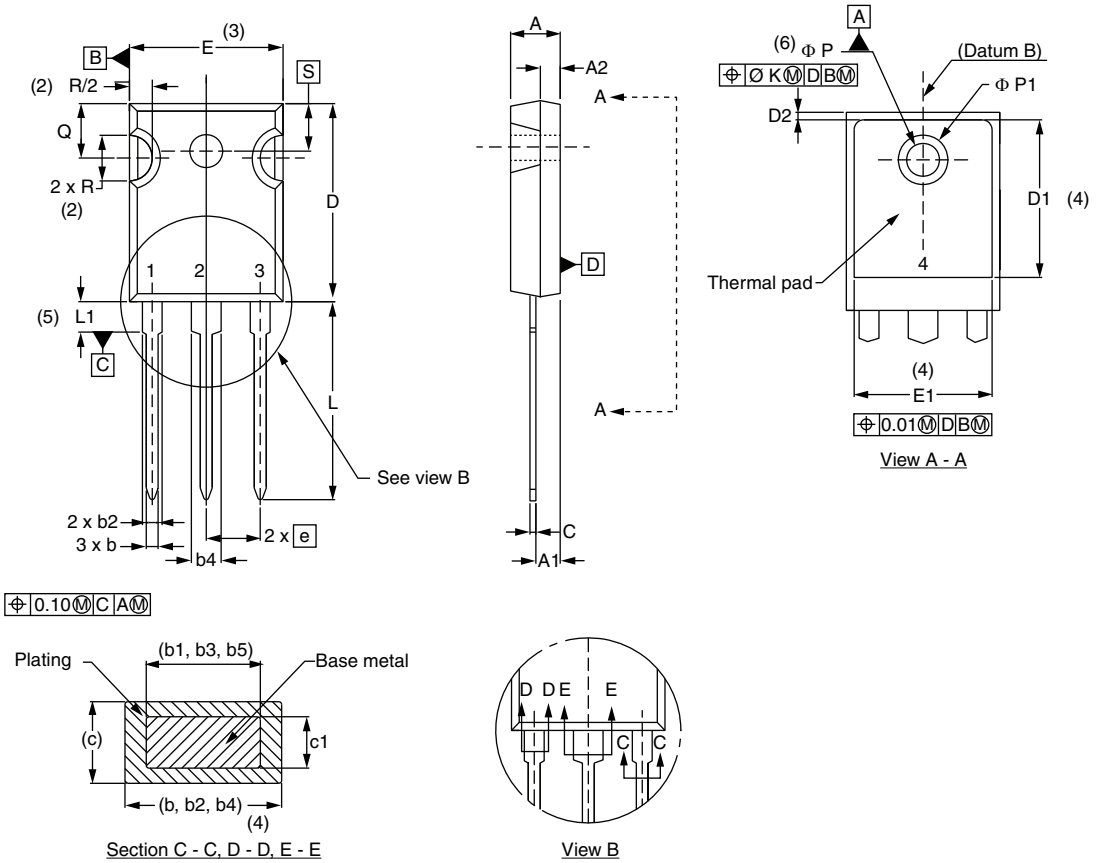
TO-247AD 3L

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	
A	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.50	2.49	0.059	0.098	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.34	0.065	0.092	
b4	2.59	3.43	0.102	0.135	
b5	2.59	3.38	0.102	0.133	
c	0.38	0.89	0.015	0.035	
c1	0.38	0.84	0.015	0.033	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4

SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	
D2	0.51	1.30	0.020	0.051	
E	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	-	
e	5.46 BSC		0.215 BSC		
Ø K	0.254		0.010		
L	19.81	20.32	0.780	0.800	
L1	3.71	4.29	0.146	0.169	
Ø P	3.56	3.66	0.14	0.144	
Ø P1	-	6.98	-	0.275	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51 BSC		0.217 BSC		

Notes

(1) Dimensioning and tolerancing per ASME Y14.5M-1994
(2) Contour of slot optional
(3) Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body
(4) Thermal pad contour optional with dimensions D1 and E1
(5) Lead finish uncontrolled in L1
(6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
(7) Outline conforms to JEDEC® outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4

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